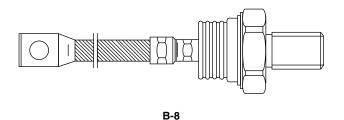


Standard Recovery Diodes, (Stud Version), 600 A



| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|--------|--|--|--|
| I _{F(AV)} | 600 A | | | |
| Package | B-8 | | | |
| Circuit configuration | Single | | | |

FEATURES

- Wide current range
- High voltage ratings up to 3200 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC® types
- · Compression bonded encapsulations
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Converters
- Power supplies
- · Machine tool controls
- High power drives
- Medium traction applications

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-----------------|-------------|--------------|-------------------|--|
| PARAMETER | TEST CONDITIONS | SD60 | LINUTO | | |
| | TEST CONDITIONS | 04 to 20 | 22 to 32 | UNITS | |
| I _{F(AV)} | | 600 | 600 | A | |
| | T _C | 92 | 54 | °C | |
| I _{F(RMS)} | | 940 | 940 | | |
| 1 | 50 Hz | 13 000 | 10 500 | Α | |
| I _{FSM} | 60 Hz | 13 600 | 11 000 | | |
| l ² t | 50 Hz | 845 | 551 | kA ² s | |
| | 60 Hz | 772 | 503 | KA-S | |
| V _{RRM} | Range | 400 to 2000 | 2200 to 3200 | V | |
| T _J | | -40 to +180 | -40 to +150 | °C | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | |
|-----------------|-----------------|--|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | $\begin{aligned} & I_{RRM} \text{ MAXIMUM} \\ \text{AT T}_{J} &= T_{J} \text{ MAXIMUM} \\ & \text{mA} \end{aligned}$ | | |
| | 04 | 400 | 500 | | | |
| | 08 | 800 | 900 | | | |
| | 12 | 1200 | 1300 | | | |
| VS-SD600N/R | 16 | 1600 | 1700 | 35 | | |
| V3-3D000IV/N | 20 | 2000 | 2100 | 33 | | |
| | 22 | 2200 | 2300 | | | |
| | 28 | 2800 | 2900 | | | |
| | 32 | 3200 | 3300 | | | |



| FORWARD CONDUCTION | | | | | | | |
|--|---------------------|--|------------------------|---|----------|----------|-------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | SD600N/R | | 0N/R | |
| PARAMETER | STINIBUL | | TEST CONDITIONS | | 04 to 20 | 22 to 32 | UNITS |
| | | | | | 600 | | Α |
| Maximum average forward current | | 180° conduction, half sine wave | | 92 | 54 | °C | |
| at case temperature | I _{F(AV)} | 160 Condi | uction, nan sine | e wave | 570 | 375 | Α |
| | | | 100 | | °C | | |
| Maximum RMS forward current | I _{F(RMS)} | DC at T _C = | 75 °C (04 to 2 | 0), T _C = 36 °C (25 to 32) | 94 | 10 | |
| | | t = 10 ms | No voltage | | 13 000 | 10 500 | A |
| Maximum peak, one-cycle forward, | l-ou | t = 8.3 ms | reapplied | Sinusoidal half wave, initial $T_J = T_J$ maximum | 13 600 | 11 000 | |
| non-repetitive surge current | I _{FSM} | t = 10 ms | 100 % V _{RRM} | | 10 900 | 8830 | |
| | | t = 8.3 ms | reapplied | | 11 450 | 9250 | |
| | l ² t | t = 10 ms | No voltage | | 845 | 551 | kA ² s |
| Maximum I ² t for fusing | | t = 8.3 ms | reapplied | | 772 | 503 | |
| Waxiindiii i cioi idaiiig | | t = 10 ms | 100 % V _{RRM} | | 598 | 390 | |
| | | t = 8.3 ms | reapplied | | 546 | 356 | |
| Maximum $I^2\sqrt{t}$ for fusing | I²√t | t = 0.1 to 10 ms, no voltage reapplied | | 8450 | 5510 | kA²√s | |
| Low level value of threshold voltage | V _{F(TO)1} | (16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $I_J = I_J$ maximum | | 0.78 | 0.84 | V | |
| High level value of threshold voltage | V _{F(TO)2} | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ | | 0.87 | 0.88 | | |
| Low level value of forward slope resistance | r _{f1} | (16.7 % x π x $I_{F(AV)}$ < I < π x $I_{F(AV)}$), $I_{J} = I_{J}$ maximum | | 0.35 | 0.40 | mW | |
| High level value of forward slope resistance | r _{f2} | $(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$ | | 0.31 | 0.38 | IIIVV | |
| Maximum forward voltage drop | V _{FM} | $I_{pk} = 1500 \text{ A}, T_J = T_J \text{ maximum},$ $t_p = 10 \text{ ms sinusoidal wave}$ | | 1.31 | 1.44 | V | |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|--|-------------------|---|------------|------------|---------------|
| DADAMETER | SYMBOL | TEST CONDITIONS | SD60 | UNITS | |
| PARAMETER | STIVIBUL | | 04 to 20 | 22 to 32 | UNITS |
| Maximum junction operating temperature range | TJ | | -40 to 180 | -40 to 150 | °C |
| Maximum storage temperature range | T _{Stg} | | -55 to 200 | | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 0.1 | | K/W |
| Maximum thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth, flat and greased | 0. | 04 | r √ vv |
| Maximum allowed mounting torque ± 10 % | | Not-lubricated threads | 5 | 0 | Nm |
| Approximate weight | | | 45 | 54 | g |
| Case style | | See dimensions (link at the end of datasheet) | | B-8 | |

| △R _{thJC} CONDUCTION | | | | |
|-------------------------------|-----------------------|------------------------|---------------------|-------|
| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS | UNITS |
| 180° | 0.012 | 0.008 | | |
| 120° | 0.014 | 0.014 | | |
| 90° | 0.017 | 0.019 | $T_J = T_J$ maximum | K/W |
| 60° | 0.025 | 0.026 | | |
| 30° | 0.042 | 0.042 | | |

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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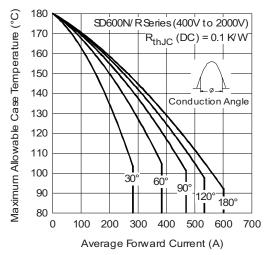


Fig. 1 - Current Ratings Characteristics

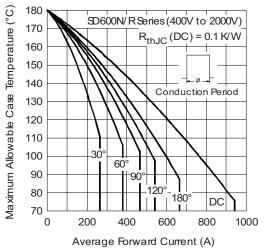


Fig. 2 - Current Ratings Characteristics

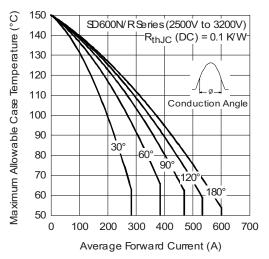


Fig. 3 - Current Ratings Characteristics

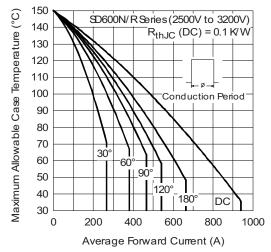


Fig. 4 - Current Ratings Characteristics

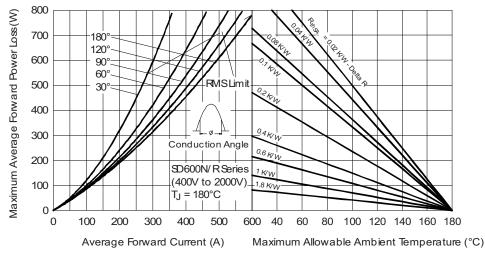


Fig. 5 - Forward Power Loss Characteristics



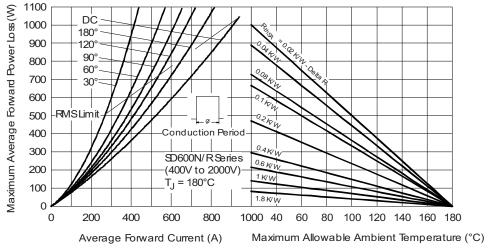


Fig. 6 - Forward Power Loss Characteristics

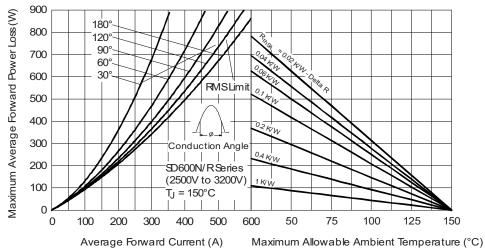


Fig. 7 - Forward Power Loss Characteristics

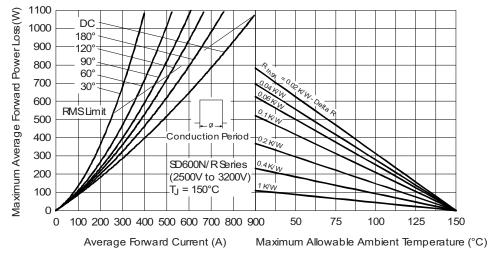


Fig. 8 - Forward Power Loss Characteristics

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Number Of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 9 - Maximum Non-Repetitive Surge Current

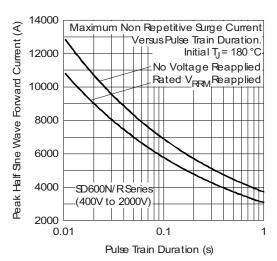


Fig. 10 - Maximum Non-Repetitive Surge Current

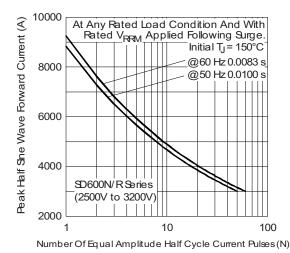


Fig. 11 - Maximum Non-Repetitive Surge Current

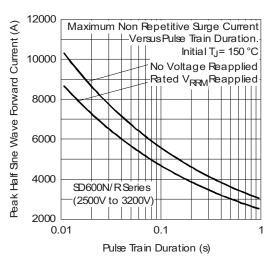


Fig. 12 - Maximum Non-Repetitive Surge Current

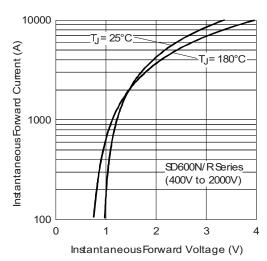


Fig. 13 - Forward Voltage Drop Characteristics

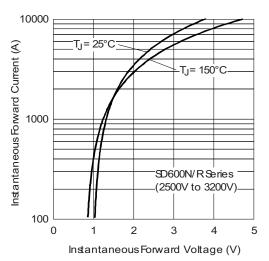


Fig. 14 - Forward Voltage Drop Characteristics

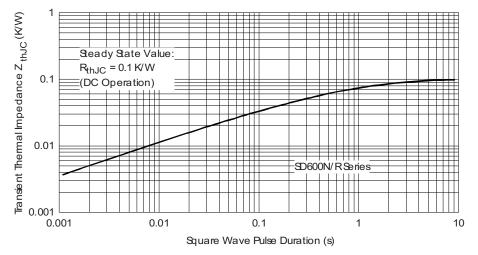
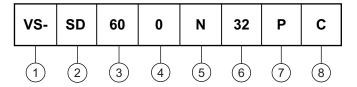


Fig. 15 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



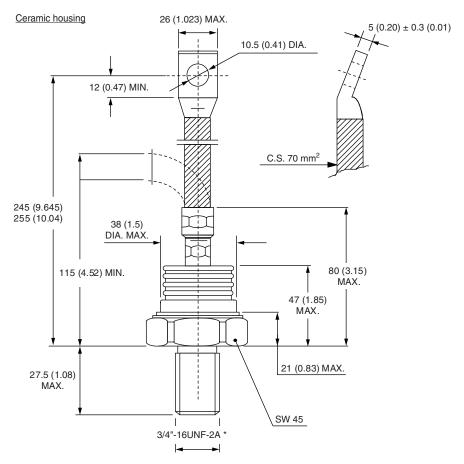
- 1 Vishay Semiconductors product
- 2 Diode
- 3 Essential part number
- 4 0 = standard recovery
- 5 • N = stud normal polarity (cathode to stud)
 - R = stud reverse polarity (anode to stud)
- 6 Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 7 P = stud base B-8 3/4" 16UNF-2A
- 8 C = ceramic cap

For metric device M24 x 1.5 contact factory

| LINKS TO RELATED DOCUMENTS | | | |
|----------------------------|--------------------------|--|--|
| Dimensions | www.vishay.com/doc?95303 | | |

B-8

DIMENSIONS in millimeters (inches)



*For metric device: M24 x 1.5 - length 21 (0.83) MAX. contact factory

Document Number: 95303 Revision: 11-Apr-08

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